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**Vishay Semiconductors** 

# Thyristor High Voltage, Phase Control SCR, 70 A



PRODUCT SUMMARY				
Package	Super TO-247			
Diode variation	Single SCR			
I <sub>T(AV)</sub>	70 A			
V <sub>DRM</sub> /V <sub>RRM</sub>	1200 V, 1600 V			
V <sub>TM</sub>	1.25 V			
I <sub>GT</sub>	100 mA			
TJ	-40 °C to 125 °C			

### FEATURES

- High surge capability
- · High voltage input rectification
- Designed and qualified according to JEDEC<sup>®</sup>-JESD47
- Material categorization: For definitions of COMPLIANT compliance please see www.vishay.com/doc?99912

### **APPLICATIONS**

- AC switches
- · High voltage input rectification (soft start)
- High current crow-bar
- Other phase-control circuits
- Designed to be used with Vishay input diodes, switches, and output rectifiers which are available in identical package outlines

### DESCRIPTION

The VS-70TPS..PbF high voltage series of silicon controlled rectifiers are specifically designed for high and medium power switching, and phase control applications.

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
I <sub>T(AV)</sub>	Sinusoidal waveform	70	А			
I <sub>RMS</sub>	Lead current limitation	75	~			
V <sub>RRM</sub> /V <sub>DRM</sub>	Range	1200/1600	V			
I <sub>TSM</sub>		1100	А			
V <sub>T</sub>	100 A, T <sub>J</sub> = 25 °C	1.4	V			
dV/dt		500	V/µs			
dl/dt		150	A/µs			
TJ		-40 to 125	°C			

VOLTAGE RATINGS						
PART NUMBER	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> AT 125 °C mA			
VS-70TPS12PbF	1200	1300	15			
VS-70TPS16PbF	1600	1700	15			

Revision: 15-Apr-14 1 Document Number: 94391 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



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ABSOLUTE MAXIMUM RATINGS	5					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average on-state current	I <sub>T(AV)</sub>	$T_{C} = 82 \ ^{\circ}C, \ 180^{\circ} \ cond$	$T_C = 82 \ ^{\circ}C$ , 180° conduction half sine wave			
Maximum continuous RMS on-state current as AC switch	I <sub>T(RMS)</sub>	Lead current limitation	Lead current limitation		75	A
Maximum peak, one-cycle	<b>I</b>	10 ms sine pulse, rate	d V <sub>RRM</sub> applied		930	
non-repetitive surge current	I <sub>TSM</sub>	10 ms sine pulse, no v	voltage reapplied		1100	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rate	d V <sub>RRM</sub> applied	Initial T <sub>J</sub> = T <sub>J</sub> maximum	4325	A <sup>2</sup> s
	1-1	10 ms sine pulse, no v	voltage reapplied	maximam	6115	
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 10 ms, no	61 150	A²√s		
Low level value of threshold voltage	V <sub>T(TO)1</sub>			0.916	v	
High level value of threshold voltage	V <sub>T(TO)2</sub>	T.I = 125 °C	1.21	v		
Low level value of on-state slope resistance	r <sub>t1</sub>	1 j = 125 °C			4.138	mΩ
High level value of on-state slope resistance	r <sub>t2</sub>					
Maximum peak on-state voltage	$V_{TM}$	100 A, T <sub>J</sub> = 25 °C	100 A, T <sub>J</sub> = 25 °C			V
Maximum rate of rise of turned-on current	dl/dt	T <sub>J</sub> = 25 °C		150	A/µs	
Maximum holding current	Ι <sub>Η</sub>	Anode supply = 6 V, resistive load, initial $I_T$ = 1 A, $T_J$ = 25 °C		200		
Maximum latching current	١L	Anode supply = 6 V, resistive load, $T_J = 25 ^{\circ}\text{C}$			400	
	I <sub>RRM</sub> /I <sub>DRM</sub>	T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>BBM</sub> /V <sub>DBM</sub>		1.0	mA
Maximum reverse and direct leakage current		$T_J = 125 \text{ °C}$ ( $T_J = T_J \text{ max., linear to 80 %}$			15	
Maximum rate of rise of off-state voltage	dV/dt	T <sub>J</sub> = 125 °C	$V_{DRM} = R_g - k = Open)$		500	V/µs

TRIGGERING					
PARAMETER	SYMBOL		TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P <sub>GM</sub>	T = 30 µs	T 00		w
Maximum average gate power	P <sub>G(AV)</sub>	i = 30 μs		2.5	vv
Maximum peak gate current	I <sub>GM</sub>			2.5	А
Maximum peak negative gate voltage	- V <sub>GM</sub>			10	
	V <sub>GT</sub>	$T_J = -40 \ ^\circ C$		1.8	V
Maximum required DC gate voltage to trigger		$T_J = 25 \ ^\circ C$	Anode supply = 6 V resistive load	1.5	
		T <sub>J</sub> = 125 °C		1.1	
		T <sub>J</sub> = - 40 °C		150	
Maximum required DC gate current to trigger	I <sub>GT</sub>	$T_J = 25 \ ^\circ C$	Anode supply = 6 V resistive load	100	mA
		T <sub>J</sub> = 125 °C		80	
Maximum DC gate voltage not to trigger	V <sub>GD</sub>			0.25	V
Maximum DC gate current not to trigger	I <sub>GD</sub>	T <sub>J</sub> = 125 °C, $V_{DRM}$ = Rated value 6			mA



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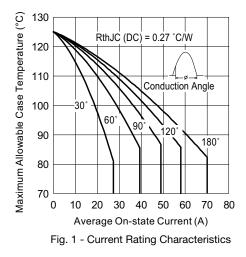
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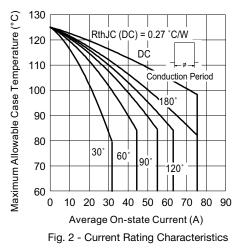
THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature	range	TJ		-40 to 125	°C	
Maximum storage temperature	range	T <sub>Stg</sub>		-40 to 150		
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation	0.27		
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		40	°C/W	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2		
				6	g	
Approximate weight				0.21	oz.	
Mounting torque	minimum			6 (5)	kgf ⋅ cm	
Mounting torque	maximum			12 (10)	(lbf · in)	
			Casa at la Super TO 247	70TPS12		
	Marking device		Case style Super TO-247	70TPS	16	

DEVICE	SINE HALF WAVE CONDUCTION RECTANGUL						ULAR WAVE CONDUCTION			UNITS	
DEVICE	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VS-70TPSPbF	0.078	0.092	0.117	0.172	0.302	0.053	0.092	0.125	0.180	0.306	°C/W

Note

• The table above shows the increment of thermal resistance R<sub>thJ-hs</sub> when devices operate at different conduction angles than DC







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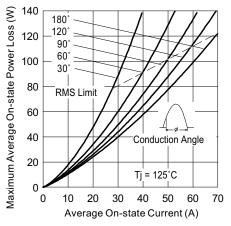
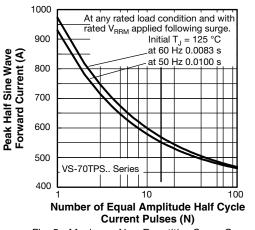


Fig. 3 - On-State Power Loss Characteristics





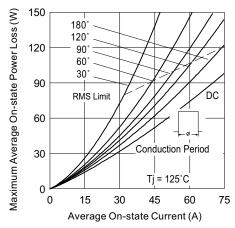


Fig. 4 - On-State Power Loss Characteristics

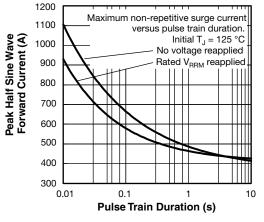
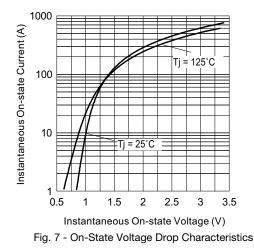
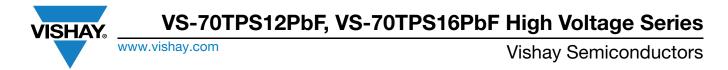


Fig. 6 - Maximum Non-Repetitive Surge Current





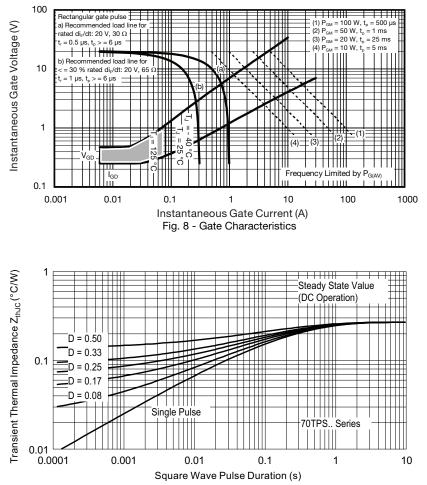


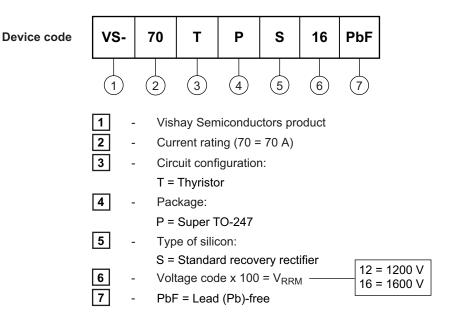
Fig. 9 - Thermal Impedance Z<sub>thJC</sub> Characteristics



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### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (example)						
PREFERED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-70TPS12PbF	25	500	Antistatic plastic tube			
VS-70TPS16PbF	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95073					
Part marking information	www.vishay.com/doc?95070				

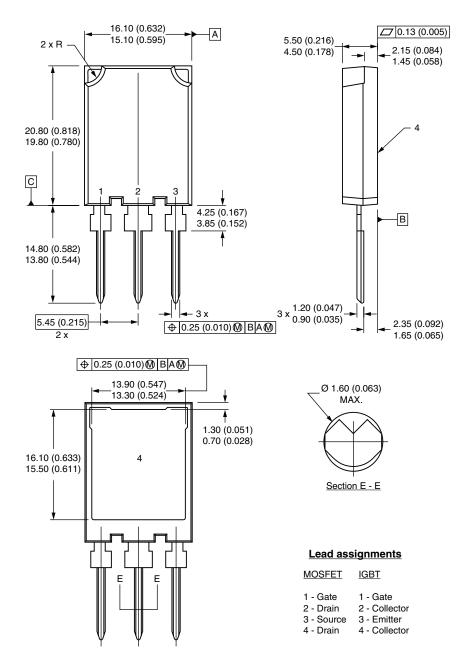


**Vishay High Power Products** 

Super TO-247

### **DIMENSIONS** in millimeters (inches)

**ISHAY** 



#### Notes

- <sup>(1)</sup> Dimension and tolerancing per ASME Y14.5M-1994
- <sup>(2)</sup> Controlling dimension: millimeter
- <sup>(3)</sup> Outline conforms to JEDEC outline TO-274AA



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